

# Rochester Electronics Manufactured Components

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Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceed the OCM data sheet.

# **Quality Overview**

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-35835
  - Class Q Military
  - Class V Space Level
- Qualified Suppliers List of Distributors (QSLD)
- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OEM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.



# LC<sup>2</sup>MOS Quad SPST Switches

# ADG441/ADG442/ADG444

### **FEATURES**

44 V supply maximum ratings V<sub>SS</sub> to V<sub>DD</sub> analog signal range Low on resistance ( $<70 \Omega$ ) Low  $\Delta R_{ON}$  (9  $\Omega$  max) Low R<sub>ON</sub> match (3 Ω max) Low power dissipation Fast switching times

toN < 110 ns  $t_{OFF} < 60 \text{ ns}$ 

Low leakage currents (3 nA max) Low charge injection (6 pC max) **Break-before-make switching action** Latch-up proof A grade Plug-in upgrade for DG201A/ADG201A, DG202A/ADG202A, DG211/ADG211A

Plug-in replacement for DG441/DG442/DG444

### **APPLICATIONS**

Audio and video switching **Automatic test equipment** Precision data acquisition **Battery-powered systems** Sample-and-hold systems **Communication systems** 

### **GENERAL DESCRIPTION**

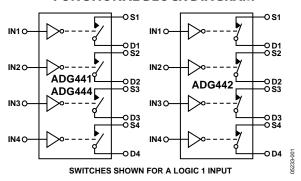
The ADG441, ADG442, and ADG444 are monolithic CMOS devices that comprise of four independently selectable switches. They are designed on an enhanced LC<sup>2</sup>MOS process that provides low power dissipation yet gives high switching speed and low on resistance.

The on resistance profile is very flat over the full analog input range, which ensures good linearity and low distortion when switching audio signals. High switching speed also makes the parts suitable for video signal switching. CMOS construction ensures ultralow power dissipation, making the parts ideally suited for portable and battery-powered instruments. The ADG441, ADG442, and ADG444 contain four independent SPST switches. Each switch of the ADG441 and ADG444 turns on when a logic low is applied to the appropriate control input. The ADG442 switches are turned on with logic high on the appropriate control input. The ADG441 and ADG444 switches

### Rev. A

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### FUNCTIONAL BLOCK DIAGRAM



differ in that the ADG444 requires a 5 V logic power supply that is applied to the V<sub>L</sub> pin. The ADG441 and ADG442 do not have a V<sub>L</sub> pin, the logic power supply is generated internally by an on-chip voltage generator.

Each switch conducts equally well in both directions when ON and has an input signal range that extends to the power supplies. In the OFF condition, signal levels up to the supplies are blocked. All switches exhibit break-before-make switching action for use in multiplexer applications. Inherent in the design is the low charge injection for minimum transients when switching the digital inputs.

### **PRODUCT HIGHLIGHTS**

- 1. Extended signal range. The ADG441A/ADG442A/ ADG444A are fabricated on an enhanced LC2MOS, trenchisolated process, giving an increased signal range that extends to the supply rails.
- 2. Low power dissipation.
- 3. Low Ron.
- 4. Trench isolation guards against latch-up for A grade parts. A dielectric trench separates the P and N channel transistors thereby preventing latch-up even under severe overvoltage conditions.
- 5. Break-before-make switching. This prevents channel shorting when the switches are configured as a multiplexer.
- 6. Single-supply operation. For applications where the analog signal is unipolar, the ADG441/ADG442/ADG444 can be operated from a single-rail power supply. The parts are fully specified with a single 12 V power supply.

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### **REVISION HISTORY**

# 5/05—Data Sheet Changed from Rev. 0 to Rev. AChanges to FormatUniversalDeleted CERDIP Package and T GradeUniversalChanges to Features and Product Highlights1Changes to Test Conditions in Table 24Changes to Figure 118Changes to Trench Isolation Section12Updated Outline Dimensions13Changes to Ordering Guide14

4/94-Revision 0: Initial Version

# **SPECIFICATIONS**

## **DUAL SUPPLY**<sup>1</sup>

 $V_{DD} = +15~V \pm 10\%, V_{SS} = -15~V \pm 10\%, V_L = +5~V \pm 10\% \ (ADG444), GND = 0~V, unless otherwise noted.$ 

Table 1.

	B Version				
Parameter	+25°C	-40°C to +85°C	Unit	Test Conditions/Comments	
ANALOG SWITCH					
Analog Signal Range		$V_{SS}$ to $V_{DD}$	V		
Ron	40		Ω typ	$V_D = \pm 8.5 \text{ V, } I_S = -10 \text{ mA}$	
	70	85	Ω max	$V_{DD} = +13.5 \text{ V}, V_{SS} = -13.5 \text{ V}$	
$\Delta R_{ON}$		4	Ωtyp	$-8.5 \text{ V} \le \text{V}_{\text{D}} \le +8.5 \text{ V}$	
		9	Ω max		
Ron Match		1	Ωtyp	$V_D = 0 \text{ V, } I_S = -10 \text{ mA}$	
		3	Ωmax		
LEAKAGE CURRENTS				$V_{DD} = +16.5 \text{ V}, V_{SS} = -16.5 \text{ V}$	
Source OFF Leakage Is (OFF)	±0.01		nA typ	·	
20 a. c. 2		. 2		$V_D = \pm 15.5 \text{ V}, V_S = \mp 15.5 \text{ V}$	
D : 0551 1 1 (055)	±0.5	±3	nA max	See Figure 15	
Drain OFF Leakage I <sub>D</sub> (OFF)	±0.01		nA typ	$V_D = \pm 15.5 \text{ V}, V_S = \mp 15.5 \text{ V}$	
	±0.5	±3	nA max	See Figure 15	
Channel ON Leakage ID, Is (ON)	±0.08		nA typ	$V_S = V_D = \pm 15.5 \text{ V}$	
	±0.5	±3	nA max	See Figure 16	
DIGITAL INPUTS					
Input High Voltage, V <sub>INH</sub>		2.4	V min		
Input Low Voltage, V <sub>INL</sub>		0.8	V max		
Input Current					
I <sub>INL</sub> or I <sub>INH</sub>		±0.00001	μA typ	$V_{IN} = V_{INL}$ or $V_{INH}$	
		±0.5	μA max		
DYNAMIC CHARACTERISTICS <sup>2</sup>			,		
ton	85		ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 35 \text{ pF}$ ;	
	110	170	ns max	$V_s = \pm 10 \text{ V}$ ; see Figure 17	
toff	45		ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 35 \text{ pF}$ ;	
	60	80	ns max	$V_s = \pm 10 \text{ V}$ ; see Figure 17	
topen	30		ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 35 \text{ pF}$ ;	
Charge Injection	1		pC typ	$V_S = 0 \text{ V}, R_S = 0 \Omega, C_L = 1 \text{ nF};$	
gy	6		pC max	$V_{DD} = +15 \text{ V}, V_{SS} = -15 \text{ V}; \text{ see Figure 18}$	
OFF Isolation	60		dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ ; $f = 1 MHz$ ; see Figure 19	
Channel-to-Channel Crosstalk	100		dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ ; $f = 1 MHz$ ; see Figure 20	
Cs (OFF)	4		pF typ	f = 1 MHz	
C <sub>D</sub> (OFF)	4		pF typ	f = 1 MHz	
C <sub>D</sub> , C <sub>s</sub> (ON)	16		pF typ	f = 1 MHz	
POWER REQUIREMENTS	10		pi typ	$V_{DD} = +16.5 \text{ V}, V_{SS} = -16.5 \text{ V}$	
I <sub>DD</sub>				Digital Inputs = $0 \text{ V or } 5 \text{ V}$	
ADG441/ADG442		80	IIA may	Digital inputs = 0 v of 5 v	
ADG441/ADG442 ADG444	0.001	OU	μΑ max μΑ typ		
ADQ <del>111</del>		2.5			
	1	2.5	μA max		
I <sub>SS</sub>	0.0001	2.5	μA typ		
L (ADC 444 Only)	1	2.5	μA max	V 55V	
I∟ (ADG444 Only)	0.001	2.5	μA typ	$V_L = 5.5 \text{ V}$	
	1	2.5	μA max		

 $<sup>^{1}</sup>$  Temperature range is: B Version:  $-40^{\circ}\text{C}$  to  $+85^{\circ}\text{C}$ .

<sup>&</sup>lt;sup>2</sup> Guaranteed by design, not subject to production test.

### SINGLE SUPPLY<sup>1</sup>

 $V_{DD}$  = +12 V  $\pm$  10%,  $V_{SS}$  = 0 V,  $V_{L}$  = +5 V  $\pm$  10% (ADG444), GND = 0 V, unless otherwise noted.

Table 2.

	B Version				
Parameter	+25°C	-40°C to +85°C	Unit	Test Conditions/Comments	
ANALOG SWITCH					
Analog Signal Range		$0$ to $V_{\text{DD}}$	V		
R <sub>ON</sub>	70		Ωtyp	$V_D = +3 \text{ V}, +8 \text{ V}, I_S = -5 \text{ mA}$	
	110	130	Ωmax	$V_{DD} = 10.8 \text{ V}$	
$\Delta R_{ON}$		4	Ωtyp	$3 \text{ V} \leq \text{V}_{\text{D}} \leq 8 \text{ V}$	
		9	Ωmax		
R <sub>ON</sub> Match		1	Ωtyp	$V_D = +6 \text{ V}, I_S = -5 \text{ mA}$	
		3	Ωmax		
LEAKAGE CURRENT				$V_{DD} = 13.2 \text{ V}$	
Source OFF Leakage Is (OFF)	±0.01		nA typ	$V_D = 12.2 \text{ V/1 V}, V_S = 1 \text{ V/12.2 V}$	
-	±0.5	±3	nA max	See Figure 15	
Drain OFF Leakage ID (OFF)	±0.01		nA typ	$V_D = 12.2 \text{ V/1 V}, V_S = 1 \text{ V/12.2 V}$	
3	±0.5	±3	nA max	See Figure 15	
Channel ON Leakage ID, Is (ON)	±0.08		nA typ	$V_S = V_D = 12.2 \text{ V/1 V}$	
<b>3</b>	±0.5	±3	nA max	Figure 16	
DIGITAL INPUTS				3	
Input High Voltage, V <sub>INH</sub>		2.4	V min		
Input Low Voltage, V <sub>INL</sub>		0.8	V max		
Input Current					
I <sub>INL</sub> or I <sub>INH</sub>		±0.00001	μA typ	$V_{IN} = V_{INL}$ or $V_{INH}$	
		±0.5	μA max		
DYNAMIC CHARACTERISTICS <sup>2</sup>			'		
ton	105		ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 35 \text{ pF}$	
	150	220	ns max	$V_S = 8 \text{ V}$ ; Figure 17	
toff	40		ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 35 \text{ pF}$	
	60	100	ns max	$V_S = 8 \text{ V}$ ; Figure 17	
<b>t</b> open	50		ns typ	$R_L = 1 \text{ k}\Omega$ , $C_L = 35 \text{ pF}$	
Charge Injection	2		pC typ	$V_S = 6 \text{ V}, R_S = 0 \Omega, C_L = 1 \text{ nF}$	
3 ,	6		pC max	$V_{DD} = 12 \text{ V}, V_{SS} = 0 \text{ V}; \text{ see Figure 18}$	
OFF Isolation	60		dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ ; see Figure 19	
Channel-to-Channel Crosstalk	100		dB typ	$R_L = 50 \Omega$ , $C_L = 5 pF$ , $f = 1 MHz$ ; see Figure 20	
C <sub>s</sub> (OFF)	7		pF typ	f=1 MHz	
C <sub>D</sub> (OFF)	10		pF typ	f = 1 MHz	
C <sub>D</sub> , C <sub>S</sub> (ON)	16		pF typ	f = 1 MHz	
POWER REQUIREMENTS			. /	V <sub>DD</sub> = 13.2 V	
I <sub>DD</sub>				Digital Inputs = 0 V or 5 V	
ADG441/ADG442		80	μA max		
ADG444	0.001		μA typ		
	1	2.5	μA max		
I∟ (ADG444 Only)	0.001		μΑ typ	$V_L = 5.5 \text{ V}$	
2 ( - 2	1	2.5	μA max		

 $<sup>^1</sup>$  Temperature range is: B Version:  $-40^\circ\text{C}$  to +85°C.  $^2$  Guaranteed by design, not subject to production test.

# **ABSOLUTE MAXIMUM RATINGS**

 $T_A = 25$ °C unless otherwise noted.

### Table 3.

Table 3.	
Parameter	Rating
V <sub>DD</sub> to V <sub>SS</sub>	44 V
V <sub>DD</sub> to GND	-0.3 V to +25 V
V <sub>SS</sub> to GND	+0.3 V to -25 V
V <sub>L</sub> to GND	$-0.3 \text{ V to V}_{DD} + 0.3 \text{ V}$
Analog, Digital Inputs	V <sub>SS</sub> – 2 V to V <sub>DD</sub> + 2 V or 30 mA, Whichever Occurs First
Continuous Current, S or D	30 mA
Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Max)	100 mA
Operating Temperature Range	
Industrial (B Version)	−40°C to +85°C
Storage Temperature Range	−65°C to +150°C
Junction Temperature	150°C
Lead Temperature, Soldering (10 sec)	300°C
Plastic Package, Power Dissipation	470 mW
$\theta_{JA}$ , Thermal Impedance	177°C/W
Lead Temperature, Soldering (10 sec)	260°C
SOIC Package, Power Dissipation	600 mW
$\theta_{JA}$ , Thermal Impedance	77°C/W
Lead Temperature, Soldering	
Vapor Phase (60 sec)	215°C
Infrared (15 sec)	220°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those listed in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Only one absolute maximum rating may be applied at any one time.

Table 4. Truth Table

ADG441/ADG444 IN	ADG442 IN	Switch Condition	
0	1	ON	
1	0	OFF	

### **ESD CAUTION**

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



# PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

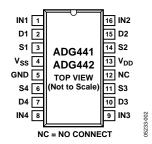


Figure 2. ADG441/ADG442 (DIP/SOIC)

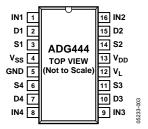


Figure 3. ADG444 (DIP/SOIC)

Table 5. ADG441/ADG442 Pin Function Descriptions

Pin No.	Mnemonic	Description
1, 8, 9, 16	IN1 to IN4	Logic Control Input.
2, 7, 10, 15	D1 to D4	Drain Terminal. May be an input or output.
3, 6, 11, 14	S1 to S4	Source Terminal. May be an input or output.
4	V <sub>SS</sub>	Most Negative Power Supply Potential in Dual Supplies. In single-supply applications, it may be connected to ground.
5	GND	Ground (0 V) Reference.
12	NC	No Connect.
13	$V_{DD}$	Most Positive Power Supply Potential.

**Table 6. ADG444 Pin Function Descriptions** 

Pin No.	Mnemonic	Description
1, 8, 9, 16	IN1 to IN4	Logic Control Input.
2, 7, 10, 15	D1 to D4	Drain Terminal. May be an input or output.
3, 6, 11, 14	S1 to S4	Source Terminal. May be an input or output.
4	V <sub>SS</sub>	Most Negative Power Supply Potential in Dual Supplies. In single-supply applications, it may be connected to ground.
5	GND	Ground (0 V) Reference.
12	$V_L$	Logic Power Supply (5 V).
13	$V_{DD}$	Most Positive Power Supply Potential.

# TYPICAL PERFORMANCE CHARACTERISTICS

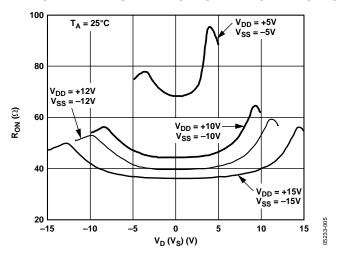


Figure 4.  $R_{ON}$  as a Function of  $V_D$  ( $V_S$ ): Dual Supply

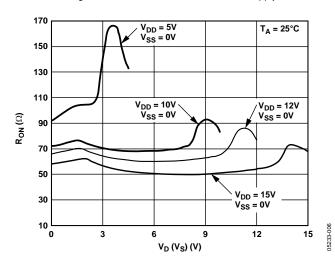


Figure 5.  $R_{ON}$  as a Function of  $V_D$  ( $V_S$ ): Single Supply

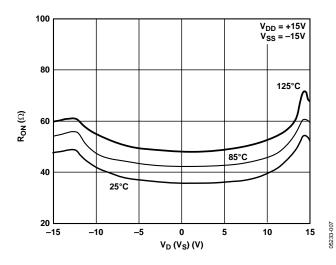


Figure 6.  $R_{ON}$  as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures

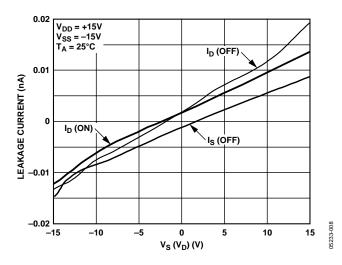


Figure 7. Leakage Currents as a Function of  $V_S(V_D)$ 

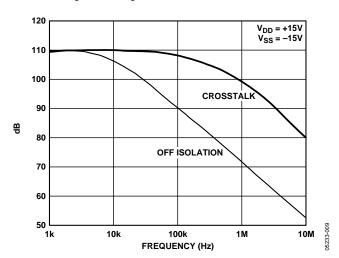


Figure 8. Crosstalk and Off Isolation vs. Frequency

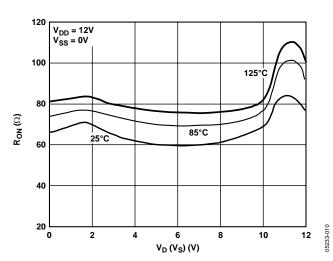


Figure 9.  $R_{ON}$  as a Function of  $V_D$  ( $V_S$ ) for Different Temperatures

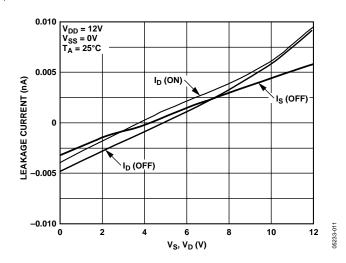


Figure 10. Leakage Currents as a Function of  $V_S$  ( $V_D$ )

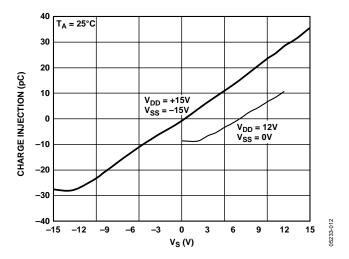


Figure 11. Charge Injection vs. Source Voltage

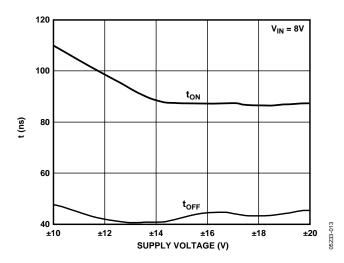


Figure 12. Switching Time vs. Bipolar Supply

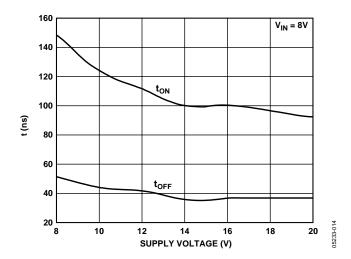
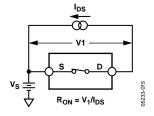
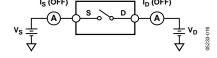


Figure 13. Switching Time vs. Single Supply

# **TEST CIRCUITS**





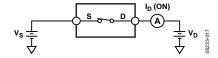


Figure 14. On Resistance

Figure 15. Off Leakage

Figure 16. On Leakage

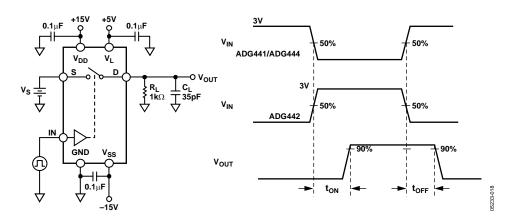


Figure 17. Switching Times

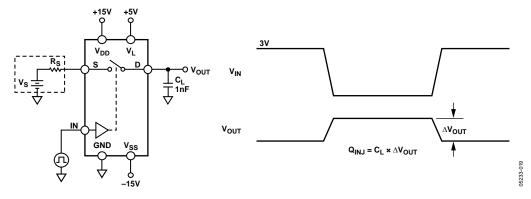


Figure 18. Charge Injection

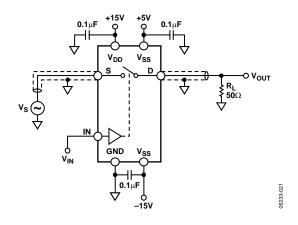


Figure 19. Off Isolation

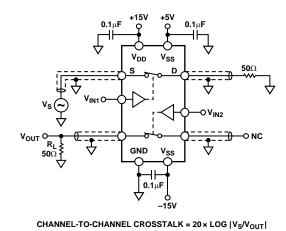


Figure 20. Channel-to-Channel Crosstalk

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# **TERMINOLOGY**

 $\mathbf{R}_{\mathbf{ON}}$ 

Ohmic resistance between D and S.

Ron Match

Difference between the Ron of any two channels.

Is (OFF)

Source leakage current with the switch OFF.

I<sub>D</sub> (OFF)

Drain leakage current with the switch OFF.

I<sub>D</sub>, I<sub>S</sub> (ON)

Channel leakage current with the switch ON.

 $V_D(V_S)$ 

Analog voltage on Terminals D, S.

Cs (OFF)

OFF switch source capacitance.

C<sub>D</sub> (OFF)

OFF switch drain capacitance.

 $C_D$ ,  $C_S$  (ON)

ON switch capacitance.

 $t_{ON}$ 

Delay between applying the digital control input and the output switching on.

 $t_{OFF}$ 

Delay between applying the digital control input and the output switching off.

**t**open

Break-before-make delay when switches are configured as a multiplexer.

Crosstalk

A measure of unwanted signal which is coupled through from one channel to another as a result of parasitic capacitance.

**Off Isolation** 

A measure of unwanted signal coupling through an OFF switch.

**Charge Injection** 

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

# TRENCH ISOLATION

In the ADG441A, ADG442A, and ADG444A, an insulating oxide layer (trench) is placed between the NMOS and the PMOS transistors of each CMOS switch. Parasitic junctions, which occur between the transistors in junction isolated switches, are eliminated, and the result is a completely latch-up proof switch.

In junction isolation, the N and P wells of the PMOS and NMOS transistors form a diode that is reverse-biased under normal operation. However, during overvoltage conditions, this diode becomes forward-biased. A silicon-controlled rectifier (SCR) type circuit is formed by the two transistors causing a significant amplification of the current which, in turn, leads to latch-up. With trench isolation, this diode is removed, and the result is a latch-up proof switch.

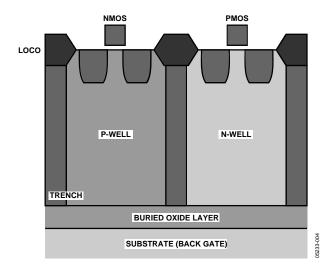
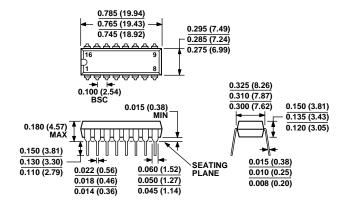


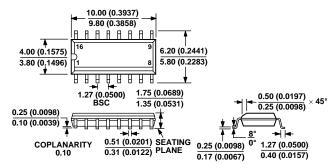
Figure 21. Trench Isolation

# **OUTLINE DIMENSIONS**



COMPLIANT TO JEDEC STANDARDS MO-095AC
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

Figure 22. 16-Lead Plastic Dual In-Line Package [PDIP] (N-16) Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-012AC
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS
(IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR
REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

Figure 23. 16-Lead Standard Small Outline Package [SOIC] (R-16) Dimensions shown in millimeters and (inches)

### **ORDERING GUIDE**

Model	Temperature Range	Package Description	Package Option
ADG441BN	−40°C to +85°C	16-Lead Plastic Dual In-Line Package (PDIP)	N-16
ADG441BR	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG441BR-REEL	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG441BRZ <sup>1</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG441BRZ-REEL <sup>1</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG441BCHIPS		DIE	
ADG441ABCHIPS <sup>2</sup>		DIE	
ADG441ABN <sup>2</sup>	-40°C to +85°C	16-Lead Plastic Dual In-Line Package (PDIP)	N-16
ADG441ABR <sup>2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG441ABR-REEL <sup>2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG441ABRZ-REEL <sup>1,2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442BN	−40°C to +85°C	16-Lead Plastic Dual In-Line Package (PDIP)	N-16
ADG442BR	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442BR-REEL	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442BRZ <sup>1</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442BRZ-REEL <sup>1</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442ABN <sup>2</sup>	-40°C to +85°C	16-Lead Plastic Dual In-Line Package (PDIP)	N-16
ADG442ABR <sup>2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442ABR-REEL <sup>2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442ABRZ <sup>1, 2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG442ABRZ-REEL <sup>1,2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444BN	−40°C to +85°C	16-Lead Plastic Dual In-Line Package (PDIP)	N-16
ADG444BR	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444BR-REEL	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444BRZ <sup>1</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444BRZ-REEL <sup>1</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444ABN <sup>2</sup>	-40°C to +85°C	16-Lead Plastic Dual In-Line Package (PDIP)	N-16
ADG444ABR <sup>2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444ABR-REEL <sup>2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444ABRZ <sup>1, 2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16
ADG444ABRZ-REEL <sup>1, 2</sup>	-40°C to +85°C	16-Lead Standard Small Outline Package (SOIC)	R-16

<b>ADG441</b>	/∆N	C442	/ΔΓ	1G <i>444</i>
ADUTT	IAD	UTTL	ML	/U444

# NOTES

**NOTES** 

